

5.8.8 Fourth order processes (5)

Starting point is the form of the term  $\tilde{K}^{(4)} p^\infty$  given by Eq. (5.58), i.e.

$$\tilde{K}^{(4)} p^\infty = -\frac{i}{\hbar} \sum_{\{\gamma_i\}} \sum_{P_1 P_2} \sum_{P_1 P_2} \sum_{\substack{\alpha_1 \sigma_1 \\ \alpha_2 \sigma_2}} \left[ \text{diagram 1} + \text{diagram 2} \right]$$

Noticeably to these two diagrams in Liouville space it correspond

$2 \cdot \underline{\underline{2^8}} = 256$  diagrams in Fock space! (\*)

Recall that in second order we had  $2 \cdot 2^2 = 8$  different contributions in Fock space

In general which diagram class is relevant depends on the considered gate and bias voltages.

We distinguish them by the the difference

$$\Delta N = N_b - N_a$$

(Specifically) *Simplicity* *we then consider  $N_a = N_b$*

$\Delta N = 0$  *interchanging processes*

$\Delta N = \pm 1$  *cotunneling assisted sequential tunneling*

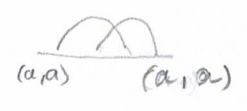
$\Delta N = \pm 2$  *pair tunneling*

4th order element

Specifically:

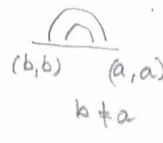
$\Delta N = 0$

cotunneling (COT) processes



$\Delta N = \pm 1$

cotunneling assisted sequential tunneling (CO-ST)



$\Delta N = \pm 2$

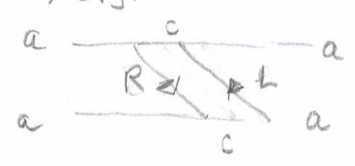
pair tunneling (PT)



a)  $\Delta N = 0$

In particular, COT processes are relevant in the situation in which second order processes are blocked due to Coulomb blockade  $\rightarrow$  the charge in the system is fixed and only processes which do not change the final particle number are relevant, E.g.

One distinguishes between

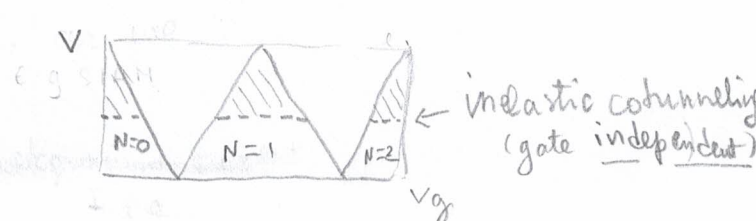
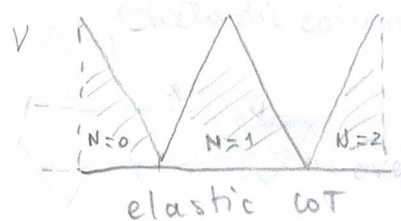


- { elastic cotunneling if  $E_b = E_a$
- { inelastic " if  $E_b \neq E_a$  (e.g.  $E_{\uparrow} \neq E_{\downarrow}$  for SIAM)

$\rightarrow$  the latter processes are relevant only at finite bias above the threshold  $eV = E_b - E_a$ ;

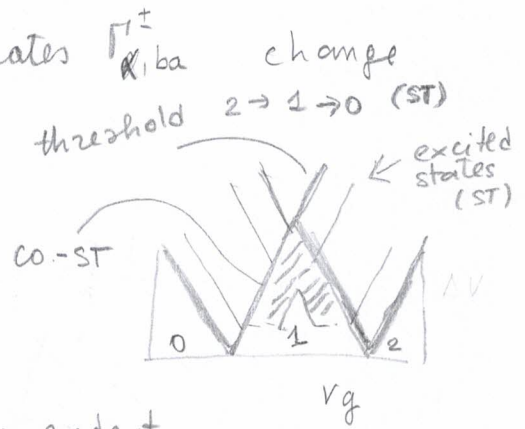
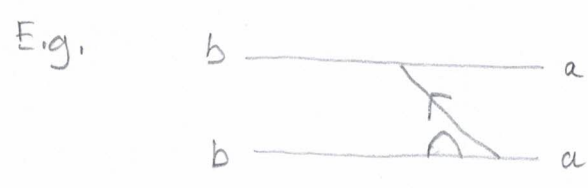
elastic cotunneling yields an overall background

e.g. SIAM



b)  $\Delta N=1$

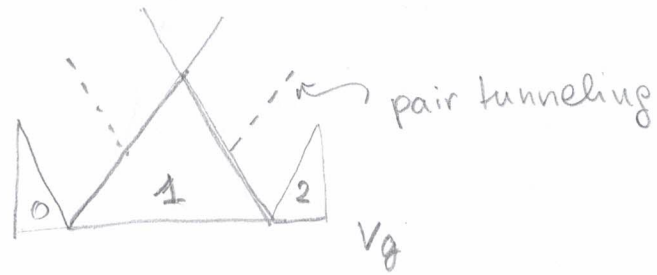
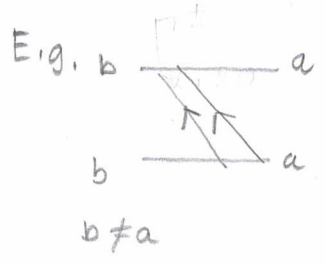
Such processes, like the second order rates  $\Gamma_{k,ba}^{\pm}$  change the final number in the dot by  $\pm 1$



Such processes are gate voltage dependent and can contribute also in the Coulomb blockade region

c)  $\Delta N=2$

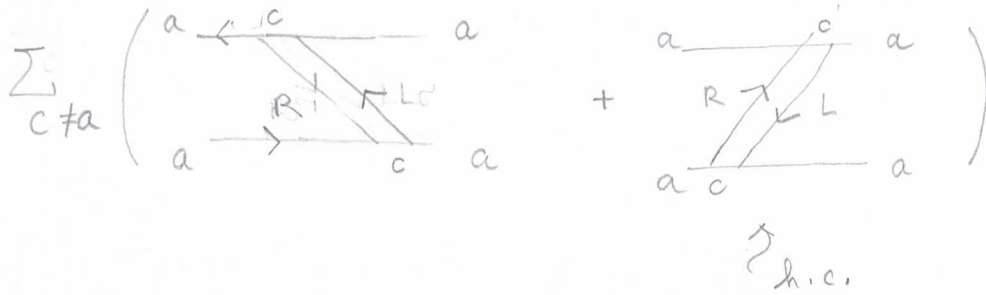
Pair tunneling transfers simultaneously two electrons, and as such give finite contributions to the rates  $\Gamma_{a,20}^{\pm}$



Similar to the Co-ST, also pair tunneling transitions depend on the gate voltage

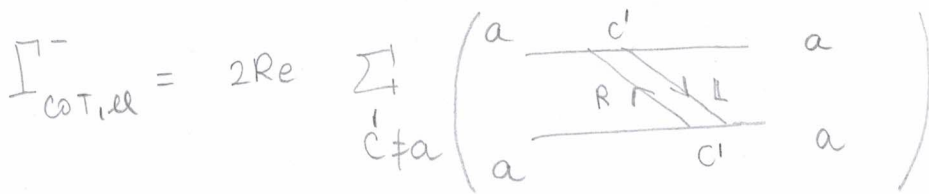
# The cotunneling kernel

We focus explicitly on the forward cotunneling process  $L \rightarrow R$  for elastic cotunneling



$$\Gamma_{cot,el}^+ = 2\text{Re} \sum_{c \neq a} \left( \text{diagram} \right) \quad \text{forward cotunneling rate}$$

similarly for the backward rate

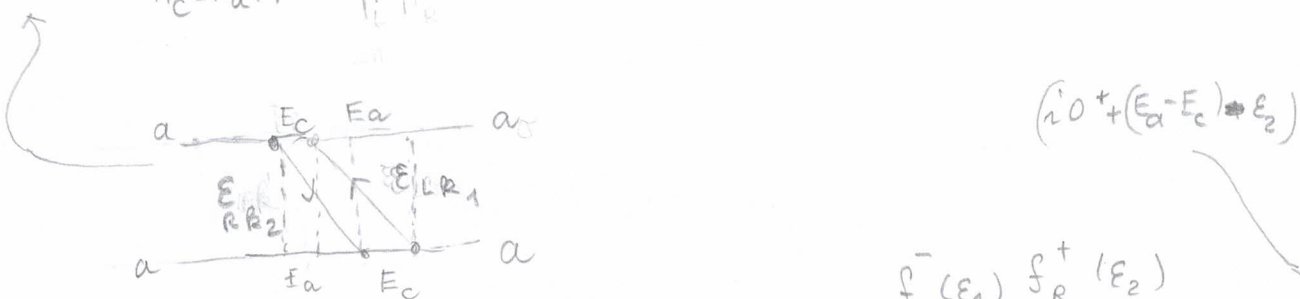


$$\Gamma_{cot,el}^- = 2\text{Re} \sum_{c' \neq a} \left( \text{diagram} \right)$$

$\Rightarrow I_{cot,el} = e (\Gamma_{cot,el}^+ - \Gamma_{cot,el}^-)$  for a fixed particle nr.  $N_a$

According to the diagrammatic rules

$$\Gamma_{cot,el}^+ = 2\text{Re} \sum_{\substack{c \neq a \\ N_c = N_a + 1}} \left( -\frac{i}{\hbar} \right) |t_L|^2 |t_R|^2 \int d\varepsilon_1 \omega_L \int d\varepsilon_2 \omega_R \frac{f_L^+(\varepsilon_1) f_R^-(\varepsilon_2)}{i0^+ + (\varepsilon_c - \varepsilon_a) - \varepsilon_1} \frac{1}{i0^+ + \varepsilon_2 - \varepsilon_1} \frac{f_R^-(\varepsilon_2)}{i0^+ + (\varepsilon_a - \varepsilon_c) - \varepsilon_2}$$



$$\Gamma_{cot,el}^- = 2\text{Re} \sum_{\substack{c' \neq a \\ N_{c'} = N_a - 1}} \left( -\frac{i}{\hbar} \right) |t_L|^2 |t_R|^2 \int d\varepsilon_1 \omega_L \int d\varepsilon_2 \omega_R \frac{f_L^-(\varepsilon_1) f_R^+(\varepsilon_2)}{(i0^+ + \varepsilon_{c'} - \varepsilon_a + \varepsilon_1)(i0^+ + \varepsilon_1 - \varepsilon_2)(i0^+ + \varepsilon_a - \varepsilon_{c'} - \varepsilon_2)}$$

i.e.,

$$\Gamma_{\text{cot}, \alpha}^+ = 2\text{Re}(-it) \frac{\Gamma_L \Gamma_R}{(2\pi)^2} \int d\varepsilon_1 \int d\varepsilon_2 \frac{f_L^+(\varepsilon_1) f_R^-(\varepsilon_2)}{(i0^+ + \varepsilon_c - \varepsilon_a - \varepsilon_1)(\varepsilon_2 - \varepsilon_1 + i0^+)(\varepsilon_a - \varepsilon_c + \varepsilon_2 + i0^+)}$$

Hence

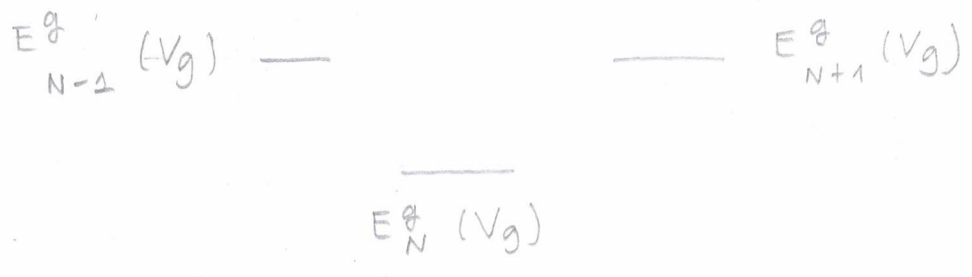
(5.79)

i)  $\Gamma_{\text{cot}, \alpha}^+ \neq 0$  if  $f_L^+(\varepsilon_1) f_R^-(\varepsilon_2) \neq 0$

$\Leftrightarrow \varepsilon_1 < \mu_L$  and  $\varepsilon_2 > \mu_R$

ii) If we are in the CB region is

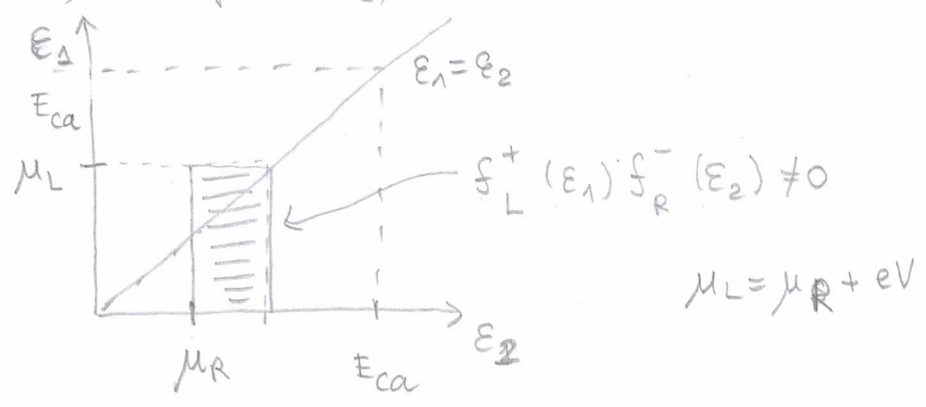
$\begin{cases} \mu_{N+1} \gg \mu_L, \mu_R \\ \mu_{N-1} \gg \mu_L, \mu_R \end{cases}$  if  $a$  is a state with  $N+1$  particles



$\Rightarrow E_c - E_a = \mu_{N+1} \gg \mu_L, \mu_R$

$E_c' - E_a = \mu_{N-1} \gg \mu_L, \mu_R$

iii) Graphically, we can represent the integrand for  $\Gamma_{\text{cot}}^+$  as



$\Rightarrow$  The contribution is maximized along the  $\varepsilon_1 = \varepsilon_2$  line. When  $V=0$ , the rectangle meets the line  $\varepsilon_1 = \varepsilon_2$  in one point only.

iv) Thus, approximately,

$$\Gamma_{\text{cot},el}^+ \approx 2\text{Re} \left( -i\hbar \frac{\Gamma_L \Gamma_R}{(2\pi)^2} \right) (-i\pi) \int d\varepsilon \frac{f_L^+(\varepsilon) f_R^-(\varepsilon)}{(E_{ca} - \varepsilon)(\varepsilon - E_{ca})}$$

neglect  $i0^+$  in outer ( $\varepsilon$ ) and use again the Sokhotski - Plemely theorem

$$= \hbar \Gamma_L \Gamma_R \int \frac{d\varepsilon}{2\pi} \frac{f_L^+(\varepsilon) f_R^-(\varepsilon)}{(E_{ca} - \varepsilon)^2}$$

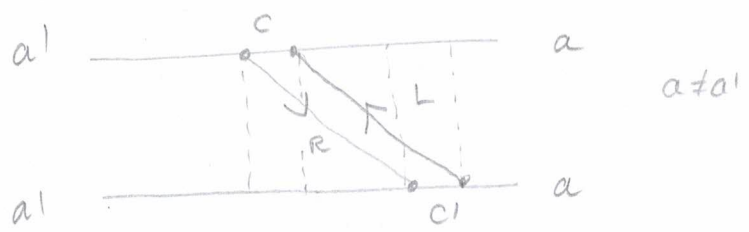
$$\Rightarrow \Gamma_{\text{cot},el}^+ \sim \hbar \frac{\Gamma_L \Gamma_R}{(E_{ca})^2} \int \frac{d\varepsilon}{2\pi} f_L^+(\varepsilon) f_R^-(\varepsilon) \quad (5.80) \quad \text{elastic cotunneling}$$

which depends on the bias voltage through the Fermi functions but not on  $V_g$

v) Similar considerations hold true for the inelastic cotunneling rates.

E.g.

$$\Gamma_{\text{cot},in}^+ = 2\text{Re} \sum_{c,c'} c c'$$



$$\Rightarrow \Gamma_{\text{cot},in}^+ = 2\text{Re} \left( -i\hbar \frac{\Gamma_L \Gamma_R}{(2\pi)^2} \right) \int d\varepsilon_1 \int d\varepsilon_2 \frac{f_L^+(\varepsilon_1) f_R^-(\varepsilon_2)}{(i0^+ + E_{c'} - E_a + \varepsilon_1)(i0^+ + E_a - E_c - \varepsilon_1 + \varepsilon_2)} \quad (5.81)$$

resonance for  $\varepsilon_2 - \varepsilon_1 = E_a - E_{c'}$   $(i0^+ + E_a) - E_c + \varepsilon_2$

Finally

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$$\Gamma_{\text{cot in}}^+ \approx -\hbar \Gamma_L \Gamma_R \int d\varepsilon \frac{f_L^+(\varepsilon) f_R^-(\varepsilon + E_{a1a})}{(E_{c1} - E_a - \varepsilon)(E_a - E_c + \varepsilon)} \quad (5.82)$$

$$2) \left\{ \begin{array}{l} \Gamma_{\text{cot in}}^+ \neq 0 \text{ if } \varepsilon > \mu_R + E_{a1a} \text{ \& } \varepsilon < \mu_L \text{ } \leftarrow \text{threshold at } eV = E_{a1a} \\ \Gamma_{\text{cot in}}^+ \approx \frac{\hbar \Gamma_L \Gamma_R}{(E_{c1} - E_a)(E_c - E_a)} \int f_L^+(\varepsilon) f_R^-(\varepsilon + E_{a1a}) d\varepsilon \end{array} \right.$$

Similar considerations apply to  $\Gamma_{\text{cot el}}^-$ ,  $\Gamma_{\text{cot in}}^-$

## 5.9 APPLICATION: THE SINGLE IMPURITY ANDERSON MODEL

Our results are very general. Exemplarily we apply them to the single impurity Anderson model (SIAM), already discussed in Ch. 4.6 using the equation of motion method (EOM).

The drawback of the EOM was that it is restricted to weak interaction:  $U \ll \Gamma$ . The advantage is that it becomes exact when  $U \rightarrow 0$ .

### Refresh

$$\hat{H}_T = \sum_{\alpha} \sum_{\vec{k}\sigma} (t_{\alpha} c_{\alpha\vec{k}\sigma}^{\dagger} d_{\sigma} + t_{\alpha}^{*} d_{\sigma}^{\dagger} \hat{c}_{\alpha\vec{k}\sigma}) = \hat{H}_{TL} + \hat{H}_{TR}$$

Further

$$\hat{H}_{TL} = \hat{L} + \hat{L}^{\dagger}, \quad \hat{H}_{TR} = \hat{R} + \hat{R}^{\dagger}$$

where  $\hat{L} = t_L c_{L\vec{k}\sigma}^{\dagger} d_{\sigma}$ ,  $\hat{R} = t_R c_{R\vec{k}\sigma}^{\dagger} d_{\sigma}$

account for outgoing processes from the quantum dot

$$\hat{H}_S = \sum_{\sigma} \tilde{\epsilon}_{\sigma} d_{\sigma}^{\dagger} d_{\sigma} + U \hat{m}_{\uparrow} \hat{m}_{\downarrow}$$

and  $\tilde{\epsilon}_{\sigma}(V_g) = \epsilon_{\sigma} - \alpha e V_g$  ( $\alpha$  is not a lead index!)

The eigenstates are thus

$$|0\rangle \rightsquigarrow E_0 = 0$$

$$|\uparrow\rangle, |\downarrow\rangle \rightsquigarrow \tilde{\epsilon}_{\uparrow}, \tilde{\epsilon}_{\downarrow}$$

$$|\uparrow\downarrow\rangle = |2\rangle \rightsquigarrow \tilde{\epsilon}_{\uparrow} + \tilde{\epsilon}_{\downarrow} + U$$

Without external magnetic field  $\epsilon_{\uparrow} = \epsilon_{\downarrow} = \epsilon_d$ .



# Current

According to (5.34) the current follows from

$$I = \text{Tr}_s \{ \tilde{\chi}_{\mathbb{I}_L}^+ \rho^\infty \} = \sum_b \left( \sum_{aa'} (\tilde{\chi}_{\mathbb{I}_L}^+)_{ba} S_{aa'} \right)$$

From the superselection rule for the elements of  $S_{aa'}$

$$\hookrightarrow S_{aa'} = \delta_{aa'} S_{aa} \quad \text{for SIAM}$$

$$\text{i.e. } S_{aa'} = \rho_{00} |0\rangle\langle 0| + \rho_{\uparrow\uparrow} |\uparrow\rangle\langle\uparrow| + \rho_{\downarrow\downarrow} |\downarrow\rangle\langle\downarrow| + \rho_{22} |2\rangle\langle 2|$$

Hence

$$I = \sum_b \sum_a (\tilde{\chi}_{\mathbb{I}_L}^+)_{ba} S_{aa} \quad (5.83)$$

$\hookrightarrow$  We need: I) diagonal elements  $S_{aa}$

in turn

II) tensor elements  $(\tilde{\chi}_{\mathbb{I}_L}^+)_{ba}$

III) the subclass of elements  $(\tilde{\chi}_{\mathbb{I}_L}^+)_{ba}$

STEP I : STATIONARY RDM FOR THE S/AM

Start from the set of coupled equations (5.28), using the superselection rule they become

$$0_{bb} = \sum_a \chi_{ba}^{ba} P_{aa} \quad (5.84)$$

using further the sum rule (5.1) with  $a=a'$

$$0 = \sum_b \chi_{ba}^{ba} \Rightarrow \chi_{aa}^{aa} = - \sum_{b \neq a} \chi_{ba}^{ba} \quad (5.85_b)$$

We thus find with  $\sigma = \uparrow, \downarrow$  and  $P_\alpha = P_{\alpha\alpha}$

$$\left\{ \begin{array}{l} 0 = - \left( \sum_{\sigma} \chi_{\sigma 0}^{\sigma 0} + \chi_{20}^{20} \right) P_0 + \sum_{\sigma} \chi_{0\sigma}^{0\sigma} P_{\sigma} + \chi_{02}^{02} P_2 \\ 0 = \chi_{\sigma 0}^{\sigma 0} P_0 - \left( \chi_{0\sigma}^{0\sigma} + \chi_{2\sigma}^{2\sigma} \right) P_{\sigma} + \chi_{\sigma 2}^{\sigma 2} P_2 \\ 0_{22} = \chi_{20}^{20} P_0 + \sum_{\sigma} \chi_{2\sigma}^{2\sigma} P_{\sigma} - \left( \chi_{02}^{02} + \sum_{\sigma} \chi_{\sigma 2}^{\sigma 2} \right) P_2 \end{array} \right. \quad (5.86)$$

Notice that due to the sum rule the sum of the columns is zero.

The terms with "-" describe processes which diminish the population  $P_\alpha$ , viceversa "+" processes increase it

↳ to solve for  $P_\alpha$  we use three of the four eqs. and the normalization condition:  $\boxed{\sum_{\alpha} P_{\alpha} = 1}$

Explicitly

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$$\begin{cases} 0 = \chi_{00}^{00} P_0 + \sum_{\sigma} \chi_{0\sigma}^{0\sigma} P_{\sigma} + \chi_{02}^{02} P_2 \\ 0 = \sum_{\sigma} \chi_{\sigma 0}^{\sigma 0} P_0 + \chi_{\sigma\sigma}^{\sigma\sigma} P_{\sigma} + \sum_{\sigma} \chi_{\sigma 2}^{\sigma 2} P_2 \\ 0 = \chi_{20}^{20} P_0 + \sum_{\sigma} \chi_{2\sigma}^{2\sigma} P_{\sigma} + \chi_{22}^{22} P_2 \end{cases}$$

and

$$1 = P_0 + \sum_{\sigma} P_{\sigma} + P_2$$

We define as  $k_{\alpha\beta}$  the matrix elements of the kernel matrix, with  $k_{\alpha\beta} \equiv \chi_{\alpha\beta}^{\alpha\beta} = (K)_{\alpha\beta}$

Further, we take e.g. the first three rows of  $K$

$$\Rightarrow \underbrace{\begin{pmatrix} k_{11} & k_{12} & k_{13} & k_{14} \\ k_{12} & k_{22} & k_{23} & k_{24} \\ k_{31} & k_{32} & k_{33} & k_{34} \\ 1 & 1 & 1 & 1 \end{pmatrix}}_{\equiv A} \begin{pmatrix} P_0 \\ P_{\uparrow} \\ P_{\downarrow} \\ P_2 \end{pmatrix} = \begin{pmatrix} 0 \\ 0 \\ 0 \\ 1 \end{pmatrix}$$

and

$$\boxed{\begin{pmatrix} P_0 \\ P_{\uparrow} \\ P_{\downarrow} \\ P_2 \end{pmatrix} = A^{-1} \begin{pmatrix} 0 \\ 0 \\ 0 \\ 1 \end{pmatrix} \quad (5.87)}$$

Further, we introduce the tunneling rates

(64)

$$\left\{ \begin{array}{l} \Gamma_{ba}^+ \equiv \mathcal{K}_{ba}^{ba} \quad \text{if } N_b > N_a \\ \Gamma_{ab}^- \equiv \mathcal{K}_{ba}^{ba} \quad \text{if } N_b < N_a \end{array} \right. \quad (5.88)$$

Thus eq. (5.86) becomes (cf. also for comparison sheet 14)

$$\left\{ \begin{array}{l} 0 = - \left( \sum_{\sigma} \Gamma_{\sigma 0}^+ + \Gamma_{20}^+ \right) P_0 + \sum_{\sigma} \Gamma_{\sigma 0}^- P_{\sigma} + \Gamma_{20}^- P_2 \\ 0 = \Gamma_{\sigma 0}^+ P_0 - \left( \Gamma_{\sigma 0}^- + \Gamma_{2\sigma}^+ \right) P_{\sigma} + \Gamma_{2\sigma}^- P_2 \\ 0 = \Gamma_{20}^+ P_0 + \sum_{\sigma} \Gamma_{2\sigma}^+ P_{\sigma} - \left( \Gamma_{20}^- + \sum_{\sigma} \Gamma_{2\sigma}^- \right) P_2 \end{array} \right. \quad (5.89)$$

Together with  $1 = \sum_{\alpha} P_{\alpha}$ ,  $P_{\alpha}$  can be expressed uniquely in terms of the rates  $\Gamma_{ab}^{\pm}$ !

E.g. 2nd order approximation  $\Rightarrow \Gamma_{20}^{\pm} = 0$  (see later)

$$\begin{pmatrix} P_0 \\ P_{\uparrow} \\ P_{\downarrow} \\ P_2 \end{pmatrix} = \frac{1}{\mathcal{W}} \begin{pmatrix} \sum_{\sigma} \Gamma_{\sigma 0}^- \Gamma_{2\sigma}^- \left( \Gamma_{\sigma 0}^- + \Gamma_{2\sigma}^+ \right) \\ \sum_{\sigma} \left( \Gamma_{\uparrow 0}^+ \Gamma_{\downarrow 0}^- \Gamma_{2\sigma}^- + \Gamma_{2\downarrow}^+ \Gamma_{2\uparrow}^- \Gamma_{\sigma 0}^+ \right) \\ \sum_{\sigma} \left( \Gamma_{\downarrow 0}^+ \Gamma_{\uparrow 0}^- \Gamma_{2\sigma}^- + \Gamma_{2\uparrow}^+ \Gamma_{2\downarrow}^- \Gamma_{\sigma 0}^+ \right) \\ \sum_{\sigma} \Gamma_{\sigma 0}^+ \Gamma_{2\sigma}^+ \left( \Gamma_{\sigma 0}^- + \Gamma_{2\sigma}^+ \right) \end{pmatrix} \quad (5.90)$$

With  $u$  a normalization constant ensuring  $\sum_a P_a = 1$ : (61)

$$N = \sum_{\sigma} \left[ \Gamma_{2\sigma}^- \left( \Gamma_{\uparrow 0}^- \Gamma_{\downarrow 0}^+ + \Gamma_{\downarrow 0}^- \Gamma_{\uparrow 0}^+ \right) + \Gamma_{\sigma 0}^- \left( \Gamma_{2\sigma}^- + \Gamma_{\bar{\sigma} 0}^+ \right) \Gamma_{2\bar{\sigma}}^+ + \Gamma_{\sigma 0}^+ \left( \Gamma_{2\uparrow}^- \Gamma_{2\downarrow}^+ + \Gamma_{2\downarrow}^- \Gamma_{2\uparrow}^+ \right) \right] \quad (5.91b)$$

where

$$\Gamma_{ab} \equiv \Gamma_{ab}^+ + \Gamma_{ab}^-$$

Further, in 2nd order it holds, cf. later. (cf. exercise sheet 14)

$$\Gamma_{ab}^{\pm} = \frac{2\pi}{\hbar} \sum_{\alpha=LIR} |t_{\alpha}|^2 \mathcal{D}_{\alpha}(\mathcal{E}_F) f_{\alpha}^{\pm}(\mathcal{E}_{ab}) = \sum_{\alpha} \Gamma_{\alpha} f_{\alpha}^{\pm}(\mathcal{E}_{ab})$$

where

$$\Gamma_{\alpha} = \frac{2\pi}{\hbar} |t_{\alpha}|^2 \mathcal{D}_{\alpha}(\mathcal{E}_F) \quad \text{and} \quad \mathcal{E}_{ab} = \mathcal{E}_a - \mathcal{E}_b$$

I.e.  $\mathcal{E}_{ab}$  is a difference of many-body energies.

↳ Populations are fully expressed in terms of rates  $\Gamma_{ab}^{\pm}$ !

### 6.3. TRANSPORT REGIMES

Attention: numbering for the SIAM is different from previous page (40)

We are now in the position of being able to investigate various transport regimes in the SIAM, by making use of the general solution for the current (6.10) or, being expressed

in terms of elements of the current kernel and of populations.

We allow a bias and gate voltage:  $\hat{H}_C \rightarrow \hat{H}_C - \alpha e V_g \hat{N} \Rightarrow \hat{H}_C = \sum_{\alpha} (E_{\alpha} - \alpha e V_g) \hat{n}_{\alpha} = \sum_{\alpha} E_{\alpha} \hat{n}_{\alpha}$

We shall consider various situations: I. Weak coupling, II. Intermediate coupling

#### 6.3.1. Weak coupling (2nd order, 4th order in $t_T \leftrightarrow$ first order, 2nd order in $\Gamma$ )

This regime is characterized by

$$\Gamma < k_B T \ll U \quad (6.23)$$

where  $\Gamma = \sum_e (\Gamma_{e,ab}^+ + \Gamma_{e,ab}^-) = \sum_e \frac{2\pi}{\hbar} |d_e|^2 (S_e^+ + S_e^-) = \sum_e \frac{2\pi}{\hbar} |d_e|^2$  total linewidth indep of a, b

#### i) Second order current

This current we have already derived and is given by (6.12) or (6.13):

$$I_e^{(2)} = e \sum_{\sigma} \left[ \Gamma_{e,100}^+ P_{00} + \Gamma_{e,20}^+ P_{0\sigma} - \Gamma_{e,100}^- P_{0\sigma} - \Gamma_{e,20}^- P_{22} \right]$$

moreover ( $E_{\uparrow} = E_{\downarrow}$ )

$$\begin{pmatrix} P_{00} \\ P_{0\sigma} \\ P_{22} \end{pmatrix} = \frac{1}{W} \begin{pmatrix} \Gamma_{00}^- & \Gamma_{20}^- \\ \Gamma_{00}^+ & \Gamma_{20}^- \\ \Gamma_{00}^+ & \Gamma_{20}^+ \end{pmatrix} \quad (6.24)$$

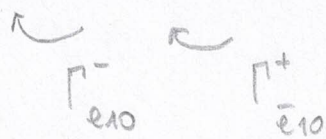
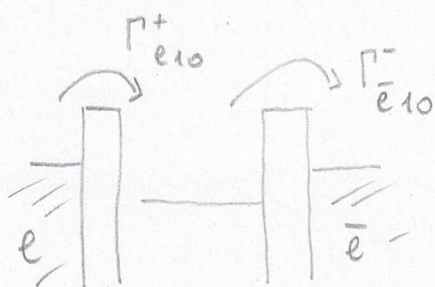
where  $W = \Gamma_{20}^- \Gamma_{00}^+ + \Gamma_{00}^+ \Gamma_{21}^+$  (6.24b)

and

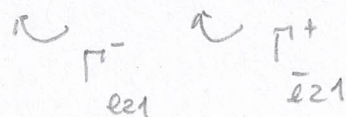
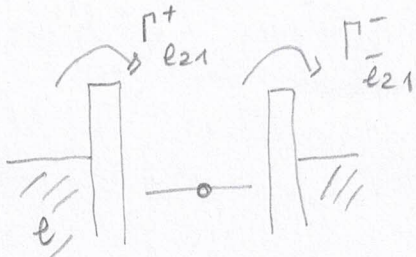
$$\Gamma_{ab} = \Gamma_{ab}^+ + \Gamma_{ab}^-, \quad \Gamma_{ab}^{\pm} = \sum_e \Gamma_{e,ab}^{\pm} \quad (6.25)$$

We thus find, with  $\Gamma_{20} = \Gamma_{21}$  etc.

$$I_e^{(2)} = \frac{2e}{\omega} \left( \Gamma_{21}^-, \Gamma_{10}^+ \right) \begin{pmatrix} \Gamma_{e10}^+ \Gamma_{\bar{e}10}^- - \Gamma_{e10}^- \Gamma_{\bar{e}10}^+ \\ \Gamma_{e21}^+ \Gamma_{\bar{e}21}^- - \Gamma_{e21}^- \Gamma_{\bar{e}21}^+ \end{pmatrix} \quad (6.26)$$



(a)



(b)

Two sequential tunneling processes are necessary to transfer charge in the forward or backward direction

example: process (a) forward

$$\Gamma_{e10}^+ \neq 0 \ \& \ \Gamma_{\bar{e}10}^- \neq 0 \Leftrightarrow f_e^+(E_{10}) \ \& \ f_{\bar{e}}^-(E_{10}) \neq 0$$

$$\Leftrightarrow E_{10}(V_g) - \mu_e \leq 0 \ \& \ E_{10}(V_g) - \mu_{\bar{e}} \geq 0$$

$\uparrow$   $\lim T \rightarrow 0$

recall that  $\mu_{\pm}(V_g) = E_{\pm}(V_g) - E_0 \Leftrightarrow (E_{\pm} \mu_e \text{ keV}_g) - E_0$

with a gate voltage which acts on  $H_{\text{sys}}$  as  $H_{\text{sys}} \rightarrow H_{\text{sys}} + \hat{N} \text{ keV}_g$

$\Rightarrow$  transport condition is (forward direction)

$$\mu_e \geq \mu_{\pm}(V_g) \geq \mu_{\bar{e}}$$

In general

$$\boxed{\mu_e \geq \mu_N(V_g) \geq \mu_{\bar{e}}}$$

forward transport (6.24)

Because  $\mu_e = \mu_0 + eV_e = \mu_0 + e\kappa_e V_e$ ,  $\mu_{\bar{e}} = \mu_0 + eV_{\bar{e}} = \mu_0 - e\kappa_{\bar{e}} V_e$ ,  $\kappa_e + \kappa_{\bar{e}} = 1$

⇒ (6.24) is also a condition on the bias voltage

Similarly for backward transport

$$\boxed{\mu_e \leq \mu_N(V_g) \leq \mu_{\bar{e}}} \quad \text{backward transport} \quad (6.24b)$$

Such conditions can be obtained also simply from energy conservation arguments,

Example: forward process a

$$E^{\text{tot}}(i) = E^{\text{tot}}(f)$$



$$E_e + E_0(V_g) = E_{\bar{e}} - \varepsilon_R + E_1(V_g) \quad E_e - \mu_e \Leftrightarrow \varepsilon_R = E_1(V_g) - E_0(V_g) = \mu_1(V_g)$$

and because  $\varepsilon_R \leq \mu_e \Rightarrow \boxed{\mu_1(V_g) \leq \mu_e = \mu_0 + eV_e}$



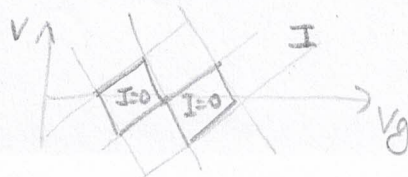
$$E^{\text{tot}}(i) = E^{\text{tot}}(f)$$

$$E_{\bar{e}} + E_1(V_g) = E_e + \varepsilon_R + E_0(V_g) \quad \Leftrightarrow \quad \varepsilon_R = \mu_1(V_g)$$

because  $\varepsilon_R \geq \mu_{\bar{e}} \Rightarrow \boxed{\mu_1(V_g) \geq \mu_{\bar{e}} = \mu_0 + eV_e}$

By elaborating on conditions (6.24) e (6.24b) with

Coulomb diamonds are obtained



$$\begin{aligned} \mu_e &= \mu_0 + e\chi_e V \\ \mu_{\bar{e}} &= \mu_0 - e\chi_{\bar{e}} V \\ \mu_N(V_g) &= \mu_N(0) - \alpha e V_g \end{aligned}$$



This condition is general and valid for second order process transferring charge in and out of the dot

$$\boxed{\mu_S \geq \mu(N|V_g) \geq \mu_D} \quad \text{for processes } N-1 \rightarrow N \rightarrow N-1$$

Can Note: Due to  $\mu_{S,D} = \mu_0 \pm e\chi_{S,D}V$ ,  $\mu(N|V_g) = E_N - E_{N-1} = \alpha eV_g$

this gives conditions on  $V_g$  and  $V$

$$\mu_0 + e\chi_S V \geq E_N - E_{N-1} = eV_g \alpha$$

source transitions  $N \rightarrow N+1$

$$V > 0$$

drain transitions  $N+1 \rightarrow N$

$$E_N - E_{N-1} = \alpha eV_g \geq \mu_0 - e\chi_D V$$

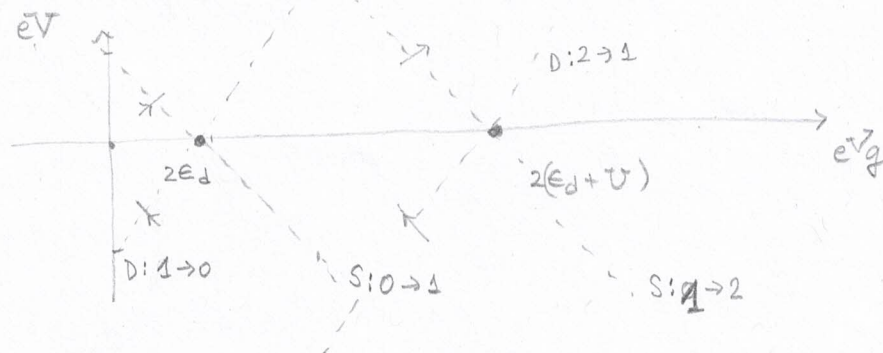
set for simplicity  $\mu_0 = 0$ ,  $\chi_S = +\chi_D = 1/2$   
 $\alpha = 1/2$

$$\begin{aligned} (\Rightarrow) V_S &= \chi_S V = \frac{1}{2} V \\ V_D &= -\chi_D V = -\frac{1}{2} V \end{aligned}$$

$$\frac{eV}{2} \geq E_1 = \frac{eV_g}{2} = \epsilon_d - \frac{eV_g}{2} \quad N=1$$

$$\frac{eV}{2} \geq (\epsilon_d + U) = \frac{eV_g}{2} \quad N=2$$

source



Adding the drain transitions

$$E_d - \frac{1}{2} eV_g \geq -\frac{e}{2} V \quad N=1 \quad \text{drain}$$

$$(E_d + U) - \frac{1}{2} eV_g \geq -\frac{e}{2} V \quad N=2$$

Note at the crossing of source and drain lines on the  $eV_g$  axis is

$$i) \frac{eV_g}{2} = \epsilon_d \quad \text{or} \quad ii) \frac{eV_g}{2} = \epsilon_d + U$$

case i)

$$\frac{eV_g}{2} = \epsilon_d \Rightarrow E_1 - \alpha eV_g = \epsilon_d - \frac{eV_g}{2} = 0 = E_0 \quad \text{i.e. } \boxed{\tilde{E}_1 = \tilde{E}_0}$$

$$\text{(and } E_2 - 2\alpha eV_g = E_2 = (2\epsilon_d + U) - 2\epsilon_d = U \quad \tilde{E}_2 = U$$

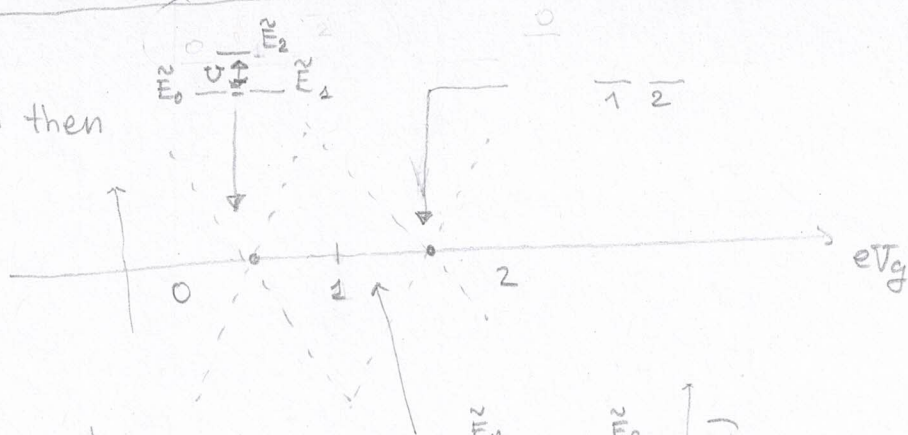
$$\text{case ii) } \frac{eV_g}{2} = \epsilon_d + U \Rightarrow E_2 - \alpha eV_g = 2\epsilon_d + U - \frac{eV_g}{2} = \epsilon_d$$

$$\Rightarrow E_2 - 2(\alpha eV_g) = \tilde{E}_2 = \epsilon_d - (\alpha eV_g) = \tilde{E}_1 \quad \text{i.e. } \boxed{\tilde{E}_2 = \tilde{E}_1}$$

$\Rightarrow$  these are called charge neutrality point as the ground states electrochem. energies for  $N$  and  $N+1$  particles are degenerate

$$\boxed{\tilde{E}_N(V_g) = \tilde{E}_{N+1}(V_g)}$$

We find then



Middle of diamond

$$eV_g = 2\epsilon_d + U$$

$$\Rightarrow \tilde{E}_2 = E_2 - 2\alpha eV_g = (2\epsilon_d + U) - eV_g = 0 = E_0$$

$$\tilde{E}_1 = E_1 - \alpha eV_g = \epsilon_d - \frac{eV_g}{2} = \epsilon_d - \epsilon_d - U = -U$$

$\Rightarrow$  Fazit: Transport condition in 2nd order

$eV > 0$

$$\boxed{\mu_S \geq \mu(N, V_g) \geq \mu_D}$$

- $\rightarrow$  Coulomb diamonds
- $\rightarrow$  transport spectroscopy

# Proportional coupling

The expression (6.26) simplifies in the case where  $\Gamma = \sum_e \Gamma_e = \Gamma_R + \Gamma_L$  can be rewritten as  $\Gamma = u_R \Gamma + u_L \Gamma$  with  $u_R + u_L = 1$ , the case of proportional coupling

$$\Rightarrow \Gamma_{e,ab}^+ = \underbrace{\frac{2\pi}{\hbar} \underbrace{d\omega_e}_{\Gamma_e} |T_e|^2}_{\Gamma_e} f_e^+(\epsilon_{ab}) = u_e \Gamma f_e^+(\epsilon_{ab}) \quad (6.28)$$

where

$$u_e + u_{\bar{e}} = 1$$

$$\text{and } \Gamma \equiv \frac{2\pi}{\hbar} \sum_e d\omega_e |T_e|^2$$

↑ no dependence on a,b but only on e

$$\Rightarrow \Gamma_{eab} = \Gamma_{eab}^+ + \Gamma_{eab}^- = u_e \Gamma f_e^+ + u_{\bar{e}} \Gamma f_{\bar{e}}^- = u_e \Gamma \text{ indep. of ab!}$$

We get from

Hence

$$\left\{ \begin{aligned} \Gamma_{e10}^+ \Gamma_{\bar{e}10}^- - \Gamma_{e10}^- \Gamma_{\bar{e}10}^+ &= \Gamma_{e10}^+ \Gamma_{\bar{e}10} - \Gamma_{e10}^- \Gamma_{\bar{e}10}^+ \stackrel{\text{prop. coup.}}{=} \Gamma (u_{\bar{e}} \Gamma_{e10}^+ - u_e \Gamma_{\bar{e}10}^+) \\ \Gamma_{e21}^+ \Gamma_{\bar{e}21}^- - \Gamma_{e21}^- \Gamma_{\bar{e}21}^+ &= \Gamma_{e21}^+ \Gamma_{\bar{e}21}^- - \Gamma_{e21}^- \Gamma_{\bar{e}21}^+ \stackrel{\text{prop. coup.}}{=} \Gamma (u_{\bar{e}} \Gamma_{e21}^- - u_e \Gamma_{\bar{e}21}^-) \end{aligned} \right.$$

(\*) add  $0 = \Gamma_{e10}^+ \Gamma_{\bar{e}10}^+ - \Gamma_{e10}^+ \Gamma_{\bar{e}10}^+$

Using (6.26) one then obtains

$$I_e^{(2)} = e N_h (u_e^- \Gamma_{e10}^+ - u_e \Gamma_{e10}^+) + e N_e (u_e \Gamma_{e21}^- - u_e^- \Gamma_{e21}^-) \quad (6.29)$$

where

$$N_e = \frac{2 \Gamma_{21}^+ \Gamma_{10}^+}{\Gamma_{21}^+ \Gamma_{10}^+ + \Gamma_{21}^- \Gamma_{10}^-} = \text{Tr} \left\{ \hat{N} \hat{\rho}_{red} \right\} \quad \text{average electron nr.} \quad (6.30a)$$

$$N_h = 2 - N_e \quad (6.30b) \quad \text{average hole nr.}$$

recalling that

$$\Gamma_{eab}^+ = u_e \Gamma f^+(E_{ab}), \quad \Gamma_{eab}^- = u_e \Gamma f^-(E_{ab})$$

we thus have

$$I_e^{(2)} = e N_h \Gamma u_e u_e^- [f_e^+(E_{10}) - f_e^-(E_{10})] + e N_e \Gamma u_e u_e^- [f_e^-(E_{21}) - f_e^+(E_{21})] \quad (6.30)$$

and, due to  $\Gamma_{ab} = \sum_e \Gamma_{eab}^e = (\sum_e u_e) \Gamma = \Gamma$ , in proportional coupling  $N_e =$

$$N_e = \frac{2 \Gamma_{10}^+}{\Gamma_{10}^+ + \Gamma_{21}^-}, \quad N_h = \frac{2 \Gamma_{21}^-}{\Gamma_{10}^+ + \Gamma_{21}^-}$$

Recalling  $f^-(x) = 1 - f^+(x)$  interesting as it shows that the current is,

$$I_e^{(2)} = e N_h \Gamma u_e u_e^- [f_e^+(E_{10}) - f_e^-(E_{10})] + e N_e \Gamma u_e u_e^- [f_e^-(E_{21}) - f_e^+(E_{21})] \quad (6.31)$$

# Integral form

$$\Gamma_{e, \sigma 0}^+ = \text{Re} \left\{ \int_{\sigma}^{\sigma} \frac{d\varepsilon}{\hbar} \dots \right\} + \dots$$

$$= \lim_{\eta \rightarrow 0^+} 2 \text{Re} \left\{ \frac{i}{\hbar} \int d\varepsilon \omega_e \frac{f_e^+(\varepsilon)}{\varepsilon - E_{\sigma 0} + i\eta} \right\} = \frac{2\pi}{\hbar} \omega_e f_e^+(E_{\sigma 0}) = U_e \Gamma f_e^+(E_{\sigma 0})$$

diagrammatic rules

and similarly for  $\Gamma_{e, \sigma 0}^-$  or  $\Gamma_{e, 2\sigma}^{\pm}$

$$I^{(2)} = N_h U_h U_e \Gamma \lim_{\eta \rightarrow 0} 2 \text{Re} \left\{ \frac{i}{\hbar} \int d\varepsilon \frac{\omega(\varepsilon)}{\varepsilon - E_{\sigma 0} + i\eta} [f_e(\varepsilon) - f_{\bar{e}}(\varepsilon)] \right\}$$

$$+ N_e U_e U_{\bar{e}} \Gamma \lim_{\eta \rightarrow 0} 2 \text{Re} \left\{ \frac{i}{\hbar} \int d\varepsilon \frac{\omega(\varepsilon)}{\varepsilon - E_{2\sigma} + i\eta} [f_e^+(\varepsilon) - f_{\bar{e}}(\varepsilon)] \right\}$$

$f^-(\varepsilon) = 1 - f^+(\varepsilon)$

Hence the final result reads:

$$I^{(2)} = e U_h U_e U_{\bar{e}} \Gamma \lim_{\eta \rightarrow 0} 2 \text{Re} \left\{ \frac{i}{\hbar} \int d\varepsilon \left[ \frac{N_h}{\varepsilon - E_{\sigma 0} + i\eta} + \frac{N_e}{\varepsilon - E_{2\sigma} + i\eta} \right] (f_e^+(\varepsilon) - f_{\bar{e}}(\varepsilon)) \right\}$$

(6.32)

This result clearly shows that the current in second order is proportional to  $\Gamma$  and to the difference of Fermi functions. The latter provide both bias voltage and temperature dependence; the gate voltage dependence is on the other hand in

$$E_{\sigma 0} = (E_{\sigma} - \alpha e V_g N) - (E_0 - \alpha e V_g (N-1)) = E_{\sigma} - E_0 - \alpha e V_g$$

# Differential conductance and linear conductance

- differential conductance  $\frac{dI}{dV}$  as obtained by differentiating (6.32) with respect to the bias voltage  $V = V_s - V_D$

- linear conductance

$$G = \lim_{V \rightarrow 0} \frac{dI}{dV} \quad (6.33)$$

From (6.32) we notice that  $f_e(\epsilon) = \frac{1}{e^{\beta(\epsilon - \mu_e)} + 1}$

$$\Rightarrow \lim_{V \rightarrow 0} f_e(\epsilon) = f(\epsilon) - \beta e V \chi_e f'(\epsilon) + O(V^2)$$

$\left\{ \begin{aligned} \mu_e &= \mu_0 + eV_e \\ &= \mu_0 + e\chi_e V \\ \mu_{\bar{e}} &= \mu_0 + eV_{\bar{e}} \\ &= \mu_0 - e\chi_{\bar{e}} V \end{aligned} \right.$

where  $f(\epsilon) = \frac{1}{e^{\beta(\epsilon - \mu_0)} + 1}$  and  $\chi_e + \chi_{\bar{e}} = 1$

such that it holds for the difference of Fermi functions

$$\lim_{V \rightarrow 0} f_e(\epsilon) - f_{\bar{e}}(\epsilon) = -\beta e V (\chi_e + \chi_{\bar{e}}) f'(\epsilon) = -\beta e V f'(\epsilon)$$

yielding

$$\left\{ \begin{aligned} G &= -\beta e^2 \text{det} \theta_{\bar{e}} \frac{\Gamma}{(2\pi/k)} \lim_{\eta \rightarrow 0} 2 \text{Re} \left\{ \frac{i}{\hbar} \int d\epsilon \left[ \frac{N_R}{\epsilon - E_{00} + i\eta} + \frac{N_e}{\epsilon - E_{21} + i\eta} \right] f'(\epsilon) \right\} \\ f'(\epsilon) &= -\frac{1}{4} \frac{1}{\text{ch}^2 \frac{\beta(\epsilon - \mu_0)}{2}} \end{aligned} \right.$$

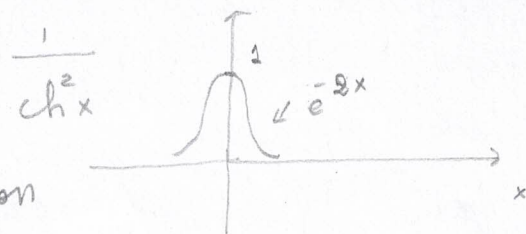
We thus obtain the final form

$$G = e^2 W_e W_e \frac{\Gamma}{2\pi\hbar} (-\beta) \frac{2}{\hbar} \lim_{\eta \rightarrow 0} \int d\varepsilon \left\{ N_R \frac{\eta}{(\varepsilon - E_{\sigma 0})^2 + \eta^2} + N_e \frac{\eta}{(\varepsilon - E_{\sigma 1})^2 + \eta^2} \right\} f'(\varepsilon)$$

or

$$G = \frac{e^2 W_e W_e}{4k_B T} \frac{\Gamma}{\pi} \lim_{\eta \rightarrow 0} \int d\varepsilon \left[ \frac{N_R \eta}{(\varepsilon - E_{\sigma 0})^2 + \eta^2} + \frac{N_e \eta}{(\varepsilon - E_{\sigma 1})^2 + \eta^2} \right] \frac{1}{ch^2 \beta \frac{(\varepsilon - \mu_0)}{2}}$$

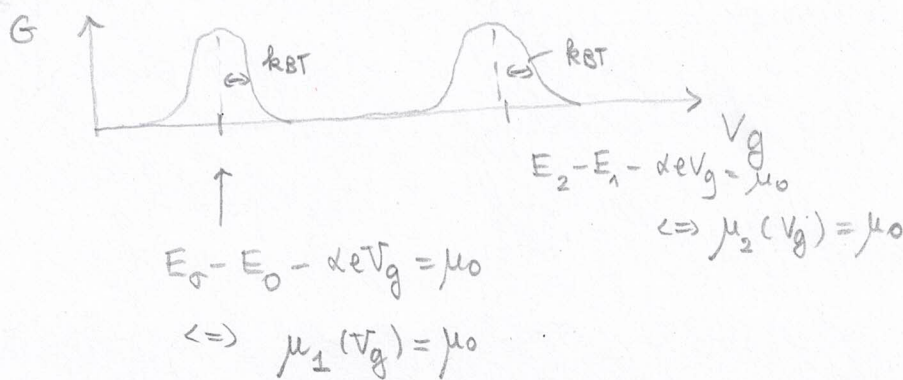
$\uparrow$  Lorentzian of width  $\eta$        $\uparrow$  peaked function of width  $k_B T$



Because  $\eta \rightarrow 0$  the Lorentzian is a  $\delta$ -function yielding the analytical expression

and  $\varepsilon = E_{\sigma 1}$  such that

$$G = \frac{e^2 W_e W_e}{4k_B T} \frac{\Gamma}{\pi} \left[ \frac{N_R}{ch^2 \beta \left( \frac{E_{\sigma 0}(V_g) - \mu_0}{2} \right)} + \frac{N_e}{ch^2 \beta \left( \frac{E_{\sigma 1}(V_g) - \mu_0}{2} \right)} \right] \quad (6.34)$$



Both the width and the height depend on  $T$ :

width  $\sim T$   
maximum  $\sim \frac{1}{T}$

